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# Shape control of cathodized germanium oxide nanoparticles

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#### **Abstract**

In this paper, hexagonal germanium dioxide (GeO<sub>2</sub>) nanostructures with different morphologies and sizes were synthesized successfully by a simple and fast electrodeposition method. We investigated the electrochemical growth mechanism, the structural and optical properties of the products through Fourier transform infrared spectroscopy (FTIR), dispersive X-ray spectroscopy (EDX), X-ray diffraction (XRD) and cathodoluminescence (CL). The results reveal that the electrodeposited GeO<sub>2</sub> nanostructures are pure, dense, and highly crystalline. The XRD analyses indicate that grown GeO<sub>2</sub> crystals only shows peaks related to  $\alpha$ -quartz structure. CL measurements exhibit strong blue and green lights emissions related to oxygen vacancies in the core of GeO<sub>2</sub> crystals. The obtained nanostructures may have potential application in future integrated optical devices.

# Introduction

Nanoscale germanium-based materials exhibit a variety of novel properties and benefit a wide range of applications [1]–[10]. Germanium dioxide (GeO<sub>2</sub>) nanostructures are versatile materials that have been explored in depth due to their unique thermal, optical and electrical properties. GeO<sub>2</sub> is thermally stable, has a high dielectric constant with large band gap energy (5 eV) [11], a high mechanical strength [12] and exhibits a refractive index that is slightly higher than that of SiO<sub>2</sub> [13], [14]. GeO<sub>2</sub> is also an attractive candidate for lithium-ion batteries (LIBs) due to its high theoretical reversible capacity (1125 mA h g<sup>-1</sup> based on 4.25 mol Li per mol Ge) and low operating voltage, as well as long cyclability [15]–[17]. In addition, this nanomaterial shows a good blue photoluminescence behavior, which is highly sought after for optical waveguides and optoelectronic communication

devices [18], especially, electro optical modulators, piezoelectric glass materials, optical fibre materials and non-linear optics [19]–[21]. Due to this all, so far, different approaches to synthesizing nanostructured GeO<sub>2</sub> have been elucidated in the literature, including thermal treatment of Ge [22], vapor transport [23], carbothermal reaction [24], carbon nanotube confined reaction of Ge [25], chemical vapor deposition [26], supercritical fluidliquid-solid synthesis [27], electro-spinning [28], e-beam evaporation [29], [30], sol-gel deposition [31], [32], radio frequency (RF) magnetron sputtering [33], [34], and laser ablation [35]. These techniques allow the synthesis of various GeO<sub>2</sub> shapes with tuned size such as nanoparticles, nanofibers, nanosheets [36], nanocubes, nanospindles, nanocapsules [37], [38], nanowires, nanorods [39], [40], and porous structures [41], [42]. However, GeO<sub>2</sub> nanoparticles fabricated from electrochemical processes have some distinctive advantages over nanoparticles fabricated by other methods mainly because (i) they are conveniently synthesized potentiostatic control, enabling electrophoretic deposition from the electrolyte, (ii) high density of nanocrystals, (iii) pure material (free of contaminants and chemical residues), (iv) high specific surface area, (v) coupled optical properties, (vi) can be transformed to powder by grinding and dispersed in a solution. In addition, the electrochemical process is standard, scalable that is already well integrated within an industrial fully automatic environment. Such a process meets the criteria, which provide an attractive solution for some specific applications.

This paper reports the successful synthesis of hexagonal GeO<sub>2</sub> nanostructures (nano-bundle aggregates and nanowires) by a simple and fast electrodeposition method with a plausible growth mechanism. The prepared GeO<sub>2</sub> nanostructures are characterized by scanning electron microscopy (SEM), Fourier transform infrared spectroscopy (FTIR), energy-

dispersive X-ray spectroscopy (EDX) and X-ray diffraction (XRD) measurements. Finally, we focus on performing a comprehensive optical characterization of GeO<sub>2</sub> nanostructures by cathodoluminescence (CL).

# **Experimental:**

GeO<sub>2</sub> nanostructures synthesis was accomplished using a conventional three-electrode single-compartment electrochemical cell. GeO2 nanostructures were potentiostatically deposited on p<sup>+</sup> type Ge wafers, (100) oriented with a nominal resistivity of 0.025  $\Omega$  cm (working electrode WE). A platinum sheet was used as counter-electrode (CE) and saturated calomel electrode (SCE) as reference electrode. All solutions were prepared from analytical grade reagents and double distilled water. As germanium tetrachloride (GeCl<sub>4</sub>) is most widely used germanium source for germanium electrodeposition in ionic liquids, electrodeposition of GeO<sub>2</sub> was conducted in a hydrogen peroxide solution containing 10% of germanium tetrachloride solution (GeCl<sub>4</sub>:H<sub>2</sub>O<sub>2</sub>, with the ratio of 1:9 by volume) at room temperature (20 °C). A wide range of GeO<sub>2</sub> morphology as a function of applied potentials was studied and a controlled structure, morphology and phase composition was sought. All potentials are reported with reference to the SCE scale. As surface conditions and activation are critical to electrocrystallisation nucleation and growth, Ge wafers were immersed in hydrofluoric acid (49%) to remove the native oxide before anodization. All deposition processes were carried out under stirring (700 rpm) using a cylindrical PTFEcoated magnetic stirrer bar of 12 mm long and 4.5 mm diameter with a pivot ring of 6 mm diameter, placed between the WE and the CE. At the end of the deposition process, all the wafers were rinsed with deionized water and dried under a high purity nitrogen gas flow. The chemical composition of the exposed surface is verified by energy-dispersive X-ray (EDX) spectroscopy. Powder X-ray diffractograms have been measured with a Philips X'Pert diffractometer in the 2θ range from 10 to 65°. The cathodoluminescence (CL) spectra and images are acquired at room temperature, in the same SEM setup as the one used for imaging the surface. Our CL system, in association with a spectrometer, allows monochromatic CL (GATAN MonoCL2) imaging as well as acquisition of CL spectra on localized spots of a sample with a spectral resolution of 0.5 nm. The accelerating voltage used in the CL characterization is 20 keV.

#### **Results:**

• *Electrochemical characterization and morphology:* 

The electrochemical characterizations such as cyclic voltammetry measurements help us to identify oxidation reduction processes potentially undergone by the system of interest and to choose an appropriate potential [43], [44]. The electrochemical window of this ionic liquid was found to be 3.5 V (-2.0 V to 1.5 V) on platinum. Figure 1(a) shows cyclic voltammetry scan performed between -1.5 V to +0.5 V at a scan rate of 20 mV s<sup>-1</sup>. The spectrum reveals a large reduction wave on the cathodic scan corresponds to two reduction reactions for  $Ge^{4+}$  ions: one leads to  $Ge^{2+}$  ions and the other to Ge [45]. The reduction waves at -0.6 and -1.1 V versus SCE were assigned to the reduction of  $Ge^{4+}$  to  $Ge^{2+}$  and  $Ge^{2+}$  to Ge, respectively [46]:

$$Ge^{4+} + 2e^{-} \rightarrow Ge^{2+}$$
 (1)

$$Ge^{2+} + 2e^{-} \rightarrow Ge$$
 (2)

The nucleation and growth of GeO<sub>2</sub> crystals are chemical steps and depend on the pH [47]. The nucleation started when the produced Ge<sup>2+</sup> ions react with OH<sup>-</sup> ions in the solution to form GeO<sub>2</sub>:

$$Ge^{2+} + 2OH^{-} \rightarrow GeO_2 \downarrow +H_2$$
 (3)

The current-time transients of the deposits produced at the -0.8, -1 and -1.2 V for the first 20 s were shown in figure 1(b). The shape of the curve can clearly indicate the nucleationgrowth mechanism. At the beginning of the applied potentials, a high cathodic current was observed for a short time of 2 s compared to the deposition of 20 s which indicates the formation of GeO2 on the surface of Ge substrate. The curves i(t) show also a normal dependence with the applied potential. The increase of the current density with the applied potential indicates that the process of the electrodeposition becomes faster. Figure 1(c-e) shows planar-view SEM images of the samples obtained at the -0.8, -1 and -1.2 V during 20s. The nanoparticles accumulate mostly on the side of the Ge wafer oriented toward the counter electrode during deposition. For all cathodic deposition potentials, the grains are assembled into a network of rounded agglomeration so-called "nano-bundle aggregates". Their density increases by increasing the cathodic potential. A closer observation of an individual nano-bundle shows different forms and shapes: (i) a nanorod -like morphology at low deposition potential (-0.8 V), with a particle size of few nanometers (Fig. 1c), (ii) a mixt of nanowires and quartz-like at deposition potential of -1 V (Fig. 1d), and (iii) a pure quartz-like morphology at high deposition potential of -1.2 V (Fig. 1e). Similar GeO<sub>2</sub> shapes have been obtained by heating of Ge powders [48]. Figure 2(a) shows a defined edge of the formed GeO<sub>2</sub> with the rest of the substrate, indicating that the nanostructures are correctly and orderly electrodeposited on the emerged part of the substrate.

In order to understand the effect of current density on the growth mechanism, the deposition time is increased from 20 s to 300 s under the same applied potentials of -0.8 V, -1 V, and -1.2 V. The resulting forms are presented in Figs. 2b, 2c and 2d, respectively. The nanorods shape obtained at -0.8 V are transformed into a criss-cross network of nanowires with an average diameter of 200 nm and an average length of 3 microns. The mixed structure obtained at -1.0 V become denser with packed wire-like particles surrounding the spherical shapes. The dimensions of the nanowires are smaller than those at -0.8 V with a diameter ranging from 50 nm to 100 nm. The quartz-like shapes obtained at -1.2 V appears to be faceted or hexagonal submicrometer crystallites with typical diameters up to 1µm. The images show that the density and the dimension of the formed nanostructures increase with the deposition time, while the different morphology obtained at each applied potential reflects a growth mechanism differs. In fact, the growth often occurs according to the 1D growth mode at low potential (-0.8V) and to the 3D growth mode at high potential (-1.2V). However, the full process could be confirmed and better understood with further experimental work.

# • Chemical and structural Analyses

In order to verify the chemical composition of the formed nanostructures, the samples were investigated and characterized through Fourier transform infrared spectroscopy (FTIR), energy-dispersive X-ray spectroscopy (EDX) and X-ray diffraction (XRD). Figure 3(a) shows the absorbance obtained by FTIR of bulk Ge sample after immersion in HF 49% solution. The dominant feature of this spectrum is at 2050 cm<sup>-1</sup>, which corresponds to the stretching mode of the GeH<sub>x</sub> bonds [49], [50]. GeH<sub>x</sub> bending modes are also present and centered at 840 cm<sup>-1</sup> [51]. Figure 3(b) shows the absorbance after anodization at -1.2 V during 300 s. The large band at 780 cm<sup>-1</sup> is attributed to the vibration of Ge-O, assuming

an oxidized surface and/or GeO<sub>2</sub> precipitates [50], [51]. Vibrational measurements show clear evidence that following the anodization process; the hydrogen-terminated Ge surface is completely converted to contain GeO<sub>x</sub> bonds.

Figures 4a-d and 4e-h show the EDX mapping of the electrodeposited samples at -0.8 V and -1.2 V, respectively. The figures reveal the uniform distribution of Ge and O contents in the formed nanowires and quartz structures. The enclosed EDX spectrum in Fig. 4i confirms the constituents of both nanostructures, which are only Ge and O since the characteristic peaks of Ge and O only appear in EDX spectra.

Powder XRD measurements were performed to investigate the crystal structure of the electrodeposited Ge oxide. The diffraction signals between  $10^{\circ}$  and  $60^{\circ}$  of the electrodeposited samples at -0.8 V and -1.2 V are shown in Fig. 5. All sharp peaks can be clearly determined as having a hexagonal GeO<sub>2</sub> with lattice constants of 4.98, 4.98, 5.64 (A°) and angles of (90°, 90°, 120°). No reflection peaks from impurities, such as unreacted Ge or other germanium oxides (tetragonal with a structure of rutile), were observed, within the detection limit of our technique (2-2.5 nm), indicating a high purity of the product [52]. The observed diffraction peaks from (100), (101), (110), and (102) planes can be indexed to those of the  $\alpha$ -quartz GeO<sub>2</sub> (space group P3221) [53]. The intensity of the (101) peak is very strong and its width at half maximum is relatively narrow, indicating a good crystallization state.

### • *Light emission from electrodeposited GeO*<sub>2</sub> *nanostructures*

To investigate the optical properties, GeO<sub>2</sub> nanostructures were examined by room-temperature cathodoluminescence spectroscopy. The morphology and CL characteristics

of the electrodeposited samples at -0.8 V and -1.2 V are reported on the spatial mapping (Fig. 6 a-d) which reveal luminescence only from the GeO<sub>2</sub> nanostructures. Fig. 6e shows the typical room temperature emission spectra from both samples. Two distinct emission peaks are observed in CL spectra, i.e. at 411 nm and 560 nm. The strong and dominated peak appeared at 560 nm (2.2 eV) can be related with the green emission while the presence of a broad peak at 411 nm (3.0 eV) can be referred as blue emission. Both blue and green light emissions are correlated to radiative recombination of defects in quartz-like GeO<sub>2</sub> crystals [18], [24], [54]. In fact, oxygen vacancies and germanium-related oxygen vacancies act as luminescence center and contribute to the observed luminescence from GeO<sub>2</sub> nanostructures such as single oxygen vacancy (OV) or double oxygen vacancy (DOV) [55]–[57]. No violet emission has been observed in the CL spectra from tetragonal GeO<sub>2</sub> crystals [48]. Because of their characteristic emission properties, these GeO<sub>2</sub> nanostructures may have potential application in future integrated optical devices.

# **Conclusions**

In summary, tuning size and morphology of  $GeO_2$  nanocrystals are made possible by electrodeposition. The formed nanostructures were characterized in detail in terms of their morphological, structural, and compositional properties which revealed that they are pure, grown in very high density, and highly crystalline. XRD analysis confirms the crystalline nature of the electrodeposited  $GeO_2$  having  $\alpha$ -quartz type hexagonal structure. The CL measurements showed that the structures have a strong blue and green light emissions assigned to radiative recombination of defects in  $GeO_2$  crystals. This study demonstrates that the electrodeposition technique can be used for the synthesis of large quantity  $GeO_2$ 

nanostructures which could be a promising candidate for the fabrication of cost-effective optoelectronics devices.

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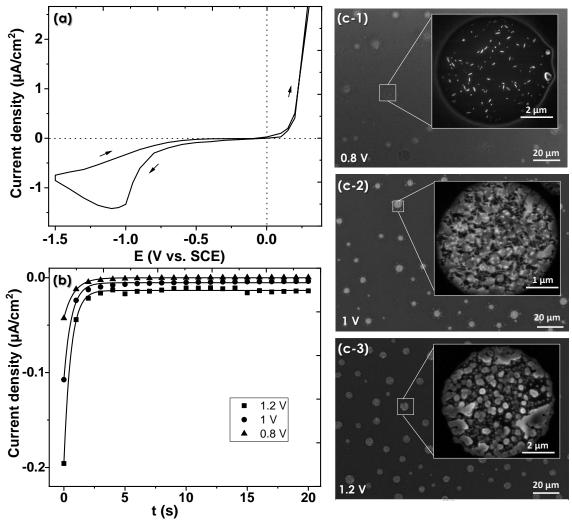


Fig. 1: (a) Cyclic voltammogram recorded in a GeCl<sub>4</sub>: $H_2O_2$  solution, with the ratio of 1:9 by volume. The potential scan rate is 20 mV s<sup>-1</sup>. (b) Current transients for GeO<sub>2</sub> nanostructures deposited at different applied potentials. Planar-view SEM images of GeO<sub>2</sub> nano-structures electrodeposited at -0.8 V (c), -1 V (d) and -1.2 V (e) on Ge substrate during 20 s.

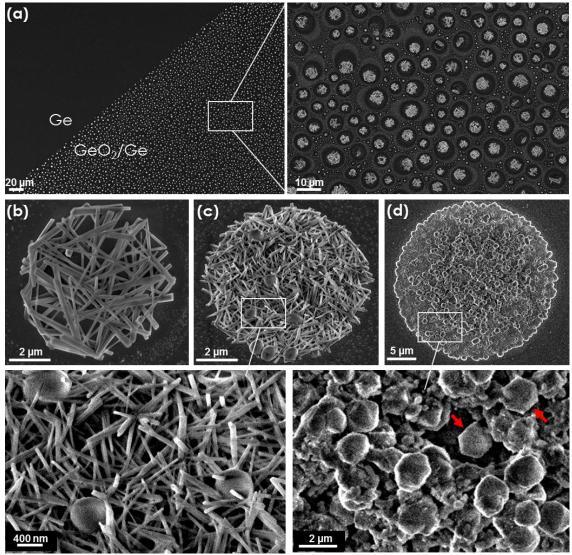


Fig. 2: Planar-view SEM images shown the emerged substrate limit in the electrolyte (a) of  $GeO_2$  nano-structures electrodeposited at -0.8 V (b), -1 V (c) and -1.2 V (d) on Ge substrate during 300 s. The inset shows high-resolution SEM image on the nano-assembled structures.

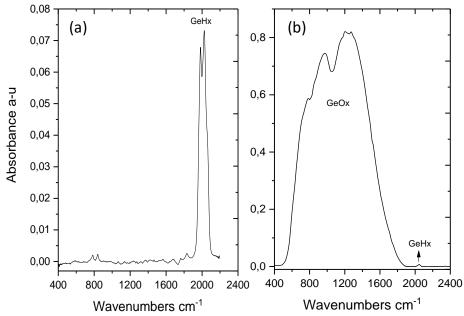


Figure 3: Typical transmission-FTIR spectra of the Ge surface before (a) and after electrodeposition of  $GeO_2$  nanostructures at -1.2 V during 300 s (b), which is dominated by a large band correlated to the vibration of Ge-O bonds.

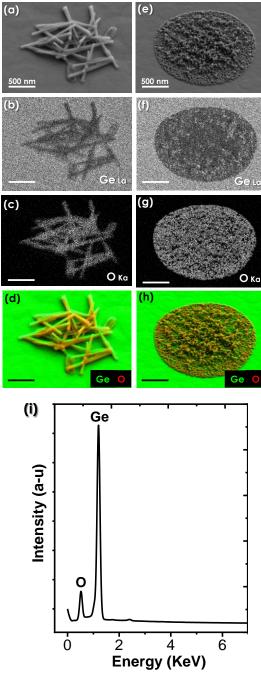


Fig. 4: EDX mapping of  $GeO_2$  nanowires (a) and quartz structures (e) electrodeposited at 0.8 V and 1.2 V respectively. The top view SEM image and the EDX element maps for (b,c) Ge, (f,g) O elements, (d,h) a mixture of Ge and O and (i) EDX spectra acquired in SEM at the top view sample.

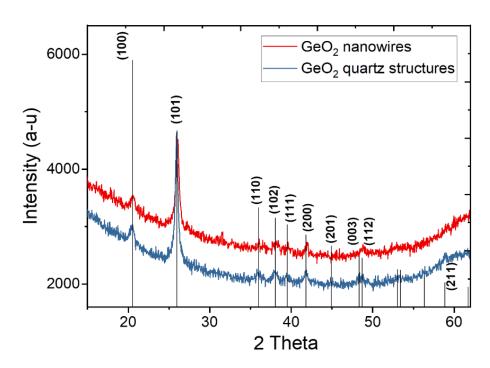


Fig. 5: Powder XRD of  $GeO_2$  nanowires and quartz structures electrodeposited at  $0.8\ V$  and  $1.2\ V$  respectively.

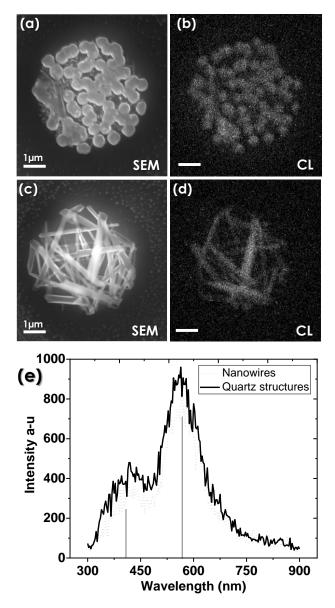


Fig. 6: SEM and CL micrographs taken from the top surface of  $GeO_2$  nanowires (a,b) and quartz structures (c, d) electrodeposited at 0.8 V and 1.2 V respectively. (e) The corresponding CL spectra.